2 Port, USB 2.0 High Speed (480 Mbps) Switch, DPDT Analog Switch

DESCRIPTION

The DG2722 is 2 port high speed analog switch optimized for USB 2.0 signal switching. The DG2722 switch is configured in DPDT. It handles bidirectional signal flow, achieving a 900 MHz - 3 dB bandwidth, and a port to port crosstalk and isolation at - 49 dB.

Processed with high density sub micron CMOS, the DG2722 provide low parasitic capacitance. Signals are routed with minimized phase distortion and attain a bit to bit skew is as low as 40 pS.

The DG2722 is designed for a wide range of operating voltages, from 2.7 V to 4.3 V that can be driven directly from one cell Li-ion battery. On-chip circuitry protects against conditions when either the D+/D- lines are shorted to the V_{BUS} at the USB port. Additionally, logic control pins (S and $\overline{OE}$) can tolerate the presence of voltages that are above the supply power rail (V+). The control logic threshold is guaranteed to be (V_{IH} = 1.3 V/min). Latch up current is 300 mA, as per JESD78, and its ESD tolerance exceeds 8 kV.

Packaged in ultra small miniQFN-10 (1.4 mm x 1.8 mm x 0.55 mm), it is ideal for portable high speed mix signal switching application.

As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device termination. The miniQFN-10 package has a nickel-palladium-gold device termination and is represented by the lead (Pb)-free “-E4” suffix to the ordering part number. The nickel-palladium-gold device terminations meet all JEDEC standards for reflow and MSL rating.

As a further sign of Vishay Siliconix's commitment, the DG2722 is fully RoHS complaint.

FEATURES

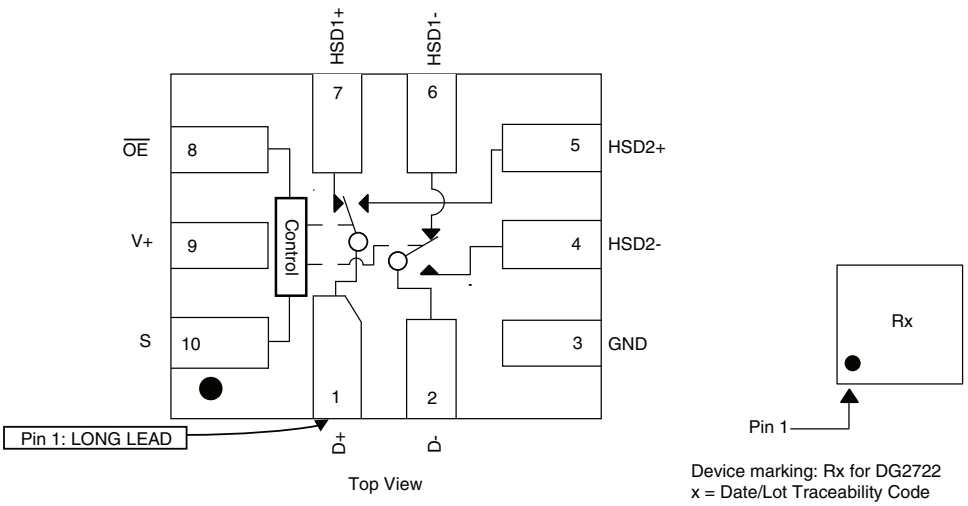
- **Halogen-free according to IEC 61249-2-21 Definition**
- Wide operation voltage range
- Low on-resistance, 7 Ω (typical at 3 V)
- Low capacitance, C_{ON} = 5.8 pF (typical)
- 3 dB high bandwidth: 900 MHz (typical)
- Low bit to bit skew: 40 pS (typical)
- Low power consumption
- Low logic threshold: V
- Power down protection: D+/D- pins can tolerate up to 5 V when V+ = 0 V
- Logic (S and $\overline{OE}$) above V+ tolerance
- 8 kV ESD protection (HBM)
- Latch-up current 300 mA per JESD78
- Lead (Pb)-free low profile miniQFN-10 (1.4 mm x 1.8 mm x 0.55 mm)
- **Compliant to RoHS Directive 2002/95/EC**

APPLICATIONS

- Cellular phones
- Portable media players
- PDA
- Digital camera
- GPS
- Notebook computer
- TV, monitor, and set top box

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

miniQFN-10L



ORDERING INFORMATION

Temp. Range	Package	Part Number
- 40 °C to 85 °C	miniQFN-10	DG2722DN-T1-E4

TRUTH TABLE

$\overline{OE}$ (Pin 8)	S (Pin 10)	Function
0	0	D+ = HSD1+ and D- = HSD1-
0	1	D+ = HSD2+ and D- = HSD2-
1	X	Disconnect

PIN DESCRIPTIONS

Pin Name	Description
$\overline{OE}$	Bus Switch Enable
S	Select Input
HSD1±, HSD2±, D±	Data Port

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

Parameter		Limit	Unit
Reference to GND	V+	- 0.3 to 5	V
	S, $\overline{OE}$, D±, HSD1±, HSD2±[a]	- 0.3 to (V+ + 0.3)	
Current (Any Terminal except S, $\overline{OE}$, D±, HSD1±, HSD2±)		30	mA
Continuous Current (S, $\overline{OE}$, D±, HSD1±, HSD2±)		± 250	
Peak Current (Pulsed at 1 ms, 10 % Duty Cycle)		± 500	
Storage Temperature (D Suffix)		- 65 to 150	°C
Power Dissipation (Packages)[b]	miniQFN-10[c]	208	mW
ESD (Human Body Model) I/O to GND		8	kV
Latch-up (Current Injection)		300	mA

Notes:
a. Signals on S, $\overline{OE}$, D±, HSD1±, HSD2± exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate 2.6 mW/°C above 70 °C.

SPECIFICATIONS (V+ = 3 V)

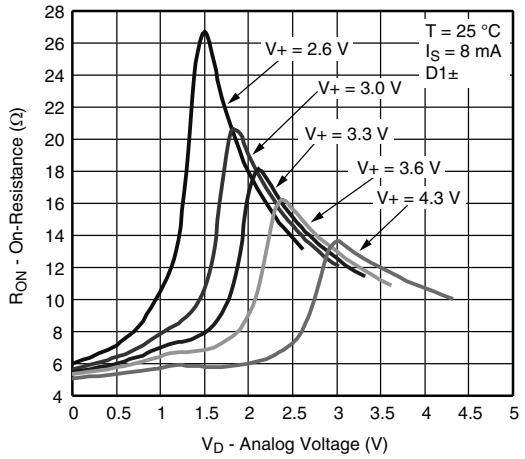
Parameter	Symbol	Test Conditions Otherwise Unless Specified	Temp.[a]	Limits - 40 °C to 85 °C Min.[b]	Typ.[c]	Max.[b]	Unit
Analog Switch							
Analog Signal Range[d]	V_{ANALOG}	$R_{DS(on)}$	Full	0		V+	V
On-Resistance	$R_{DS(on)}$	V+ = 3 V, $I_{D±}$ = 8 mA, $V_{HSD1/2±}$ = 0.4 V	Room		7	8	Ω
			Full			9	
On-Resistance Match[d]	ΔR_{ON}	V+ = 3 V, $I_{D±}$ = 8 mA, $V_{HSD1/2±}$ = 0.4 V	Room		0.8		
On-Resistance Resistance Flatness[d]	R_{ON} Flatness	V+ = 3 V, $I_{D±}$ = 8 mA, $V_{HSD1/2±}$ = 0 V, 1 V	Room		2		
Switch Off Leakage Current	$I_{(off)}$	V+ = 4.3 V, $V_{HSD1/2±}$ = 0.3 V, 3 V, $V_{D±}$ = 3 V, 0.3 V	Full	- 100		100	nA
Channel On Leakage Current	$I_{(on)}$	V+ = 4.3 V, $V_{HSD1/2±}$ = 0.3 V, 4 V, $V_{D±}$ = 4 V, 0.3 V	Full	- 200		200	
Digital Control							
Input Voltage High	V_{INH}	V+ = 3 V to 3.6 V	Full	1.3			V
		V+ = 4.3 V	Full	1.5			
Input Voltage Low	V_{INL}	V+ = 3 V to 4.3 V	Full			0.5	
Input Capacitance	C_{IN}		Full		6.5		pF
Input Current	I_{INL} or I_{INH}	V_{IN} = 0 or V+	Full	- 1		1	µA

SPECIFICATIONS (V+ = 3 V)							
Parameter	**Symbol**	**Test Conditions Otherwise Unless Specified**	**Temp.[a]**	**Limits - 40 °C to 85 °C**			**Unit**
				Min.[b]	**Typ.[c]**	**Max.[b]**	
Dynamic Characteristics							
Break-Before-Make Time[e, d]	t_{BBM}	V+ = 3 V, $V_{D1/2\pm}$ = 1.5 V, R_L = 50 Ω, C_L = 35 pF	Room		5		ns
			Full				
S, $\overline{OE}$ Turn-On Time[e, d]	t_{ON}		Room			30	
			Full				
S, $\overline{OE}$ Turn-Off Time[e, d]	t_{OFF}		Room			25	
			Full				
Charge Injection[d]	Q_{INJ}	C_L = 1 nF, R_{GEN} = 0 Ω, V_{GEN} = 0 V	Room		0.5		pC
Off-Isolation[d]	OIRR	V+ = 3 V to 3.6 V, R_L = 50 Ω, C_L = 5 pF, f = 240 MHz			- 30		dB
Crosstalk[d]	X_{TALK}				- 45		
Bandwidth[d]	BW	V+ = 3 V to 3.6 V, R_L = 50 Ω, - 3 dB			900		MHz
D+/D- On Capacitance	C_{ON}	V+ = 3.3 V, $\overline{OE}$ = 0 V, f = 240 MHz			5.8		pF
D1n, D2n Off Capacitance	C_{OFF}	V+ = $\overline{OE}$ = 3.3 V, f = 240 MHz			2.2		
Channel-to-Channel Skew[d]	$t_{SK(O)}$	V+ = 3 V to 3.6 V, R_L = 50 Ω, C_L = 5 pF			50		ps
Skew Off Opposite Transitions of the Same Output[d]	$t_{SK(p)}$				20		
Total Jitter[d]	t_J				200		
Power Supply							
Power Supply Range	V+			2.6		4.3	V
Power Supply Current	I+	V_{IN} = 0 V, or V+	Full			2	µA

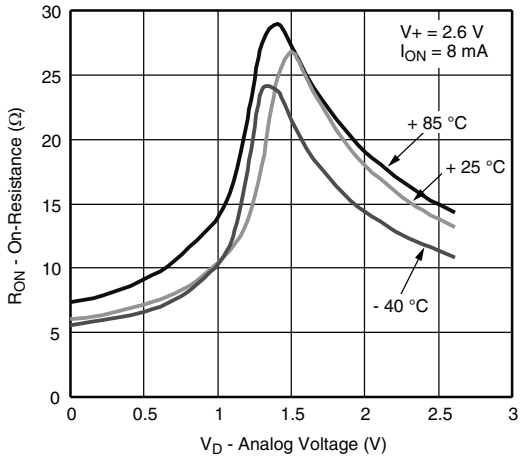
Notes:
a. Room = 25 °C, Full = as determined by the operating suffix.
b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
c. Typical values are for design aid only, not guaranteed nor subject to production testing.
d. Guarantee by design, not subjected to production test.
e. V_{IN} = input voltage to perform proper function.
f. Crosstalk measured between channels.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

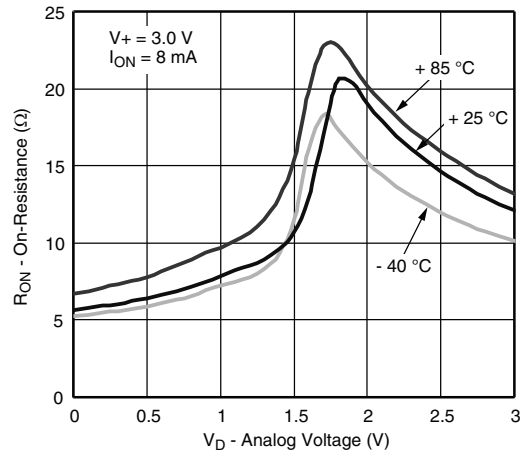
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



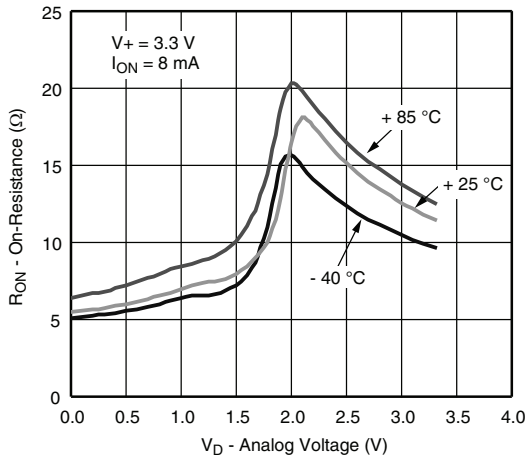
R_{ON} vs. V_D and Single Supply Voltage



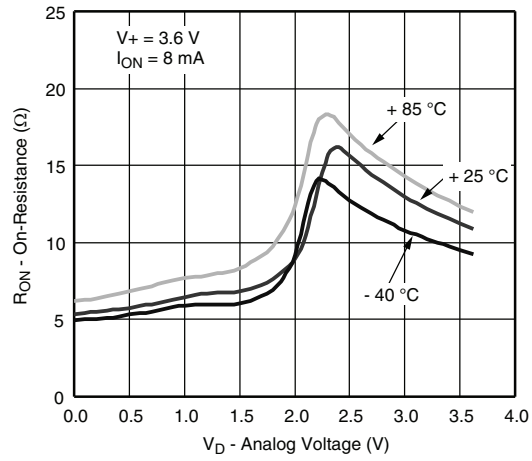
R_{ON} vs. Analog Voltage and Temperature



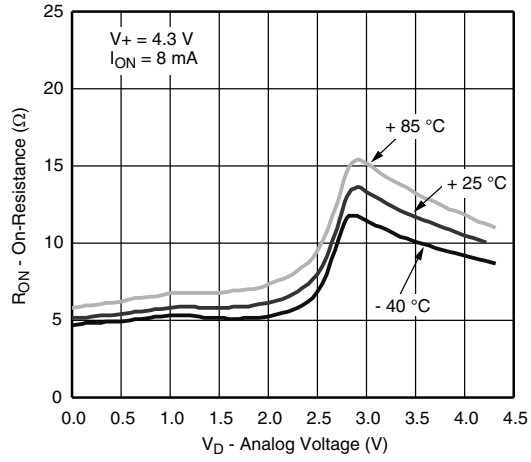
R_{ON} vs. Analog Voltage and Temperature



R_{ON} vs. Analog Voltage and Temperature

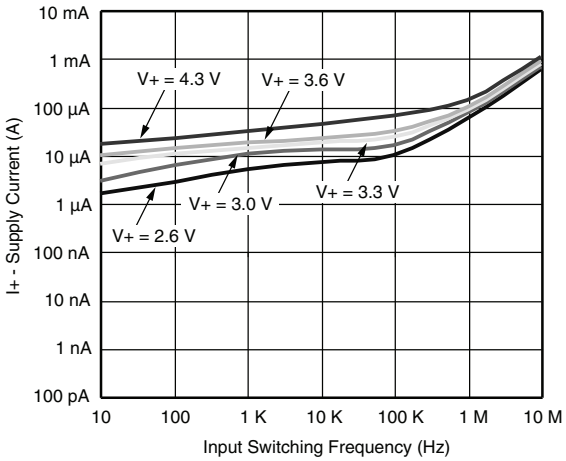


R_{ON} vs. Analog Voltage and Temperature

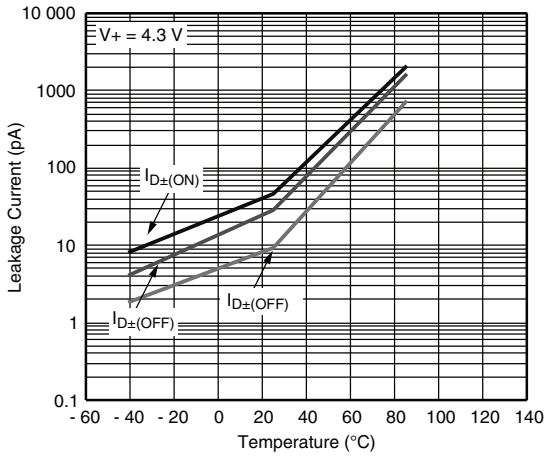


R_{ON} vs. Analog Voltage and Temperature

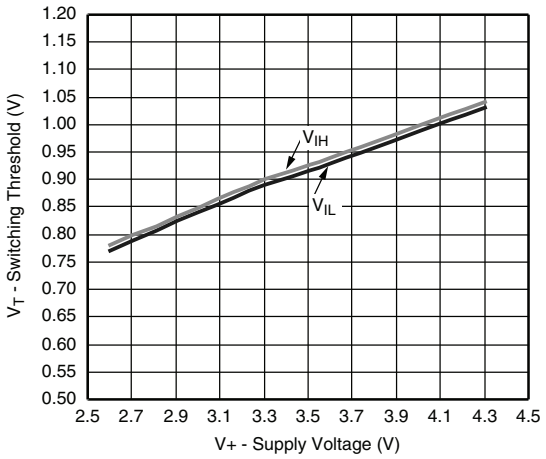
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



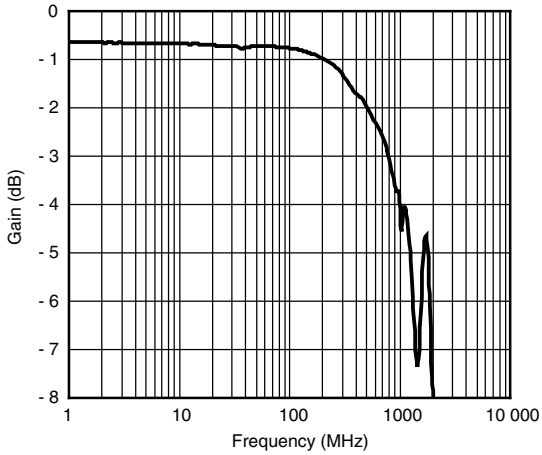
Supply Current vs. Input Switching Frequency



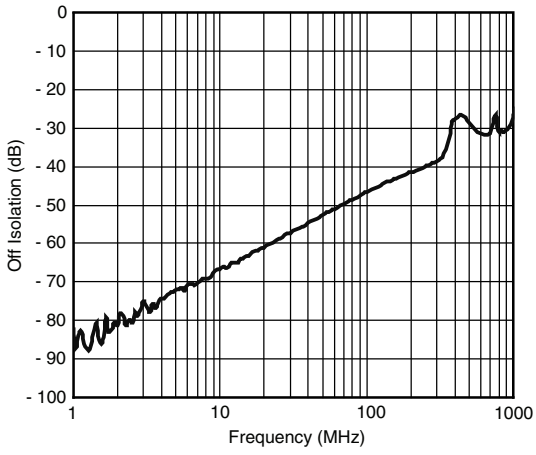
Leakage Current vs. Temperature



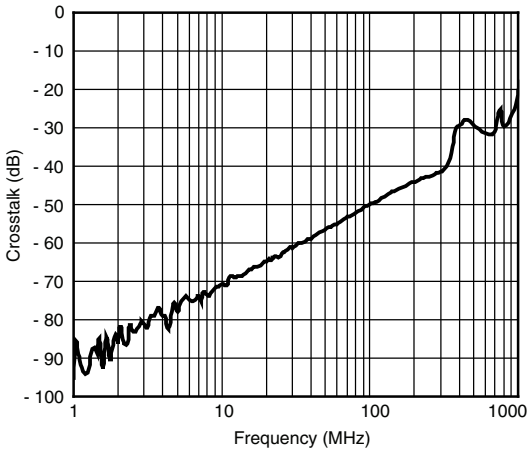
Switching Threshold vs. Supply Voltage



Gain vs. Frequency, V+ = 3.3 V

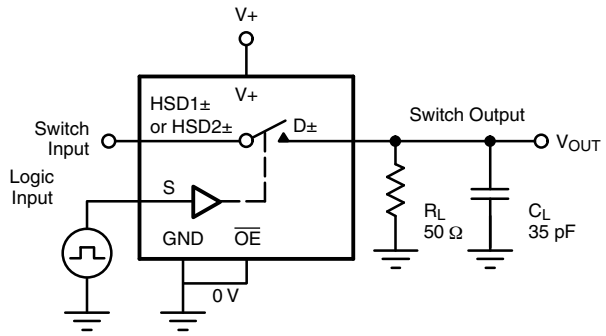


Off-Isolation, V+ = 3.3 V



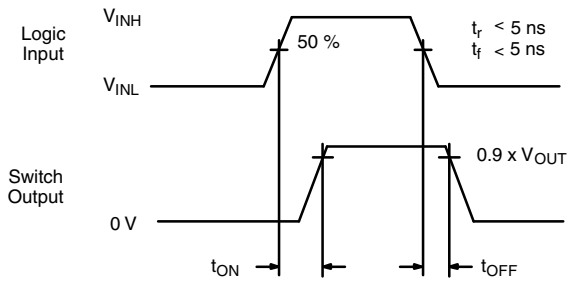
Crosstalk, V+ = 3.3 V

TEST CIRCUITS



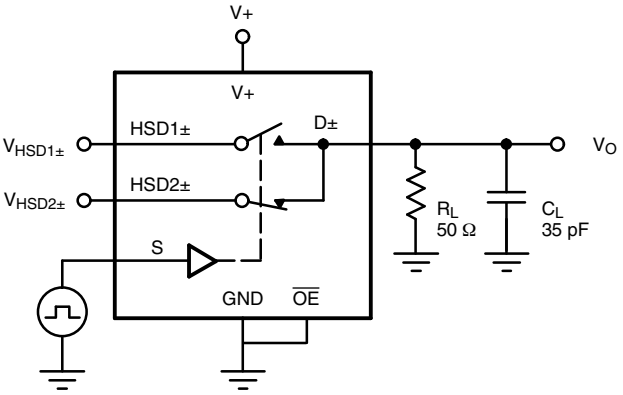
C_L (includes fixture and stray capacitance)

$$V_{OUT} = D\pm \left(\frac{R_L}{R_L + R_{ON}}\right)$$



Logic "1" = Switch on
Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time



C_L (includes fixture and stray capacitance)

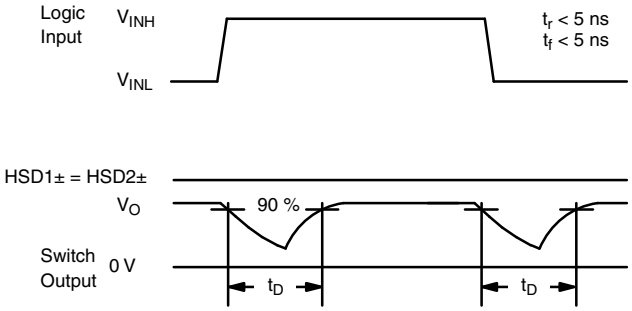
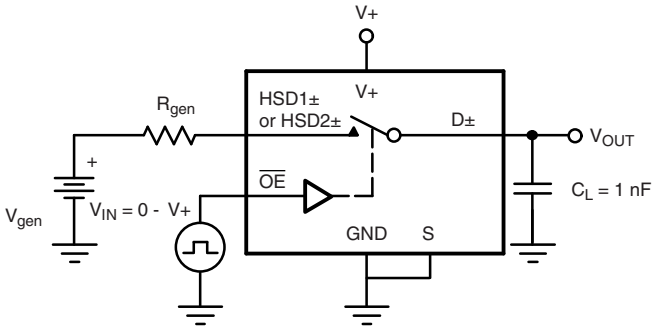
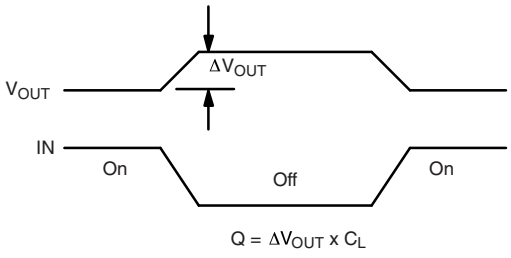


Figure 2. Break-Before-Make Interval





$Q = \Delta V_{OUT} \times C_L$

IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

TEST CIRCUITS

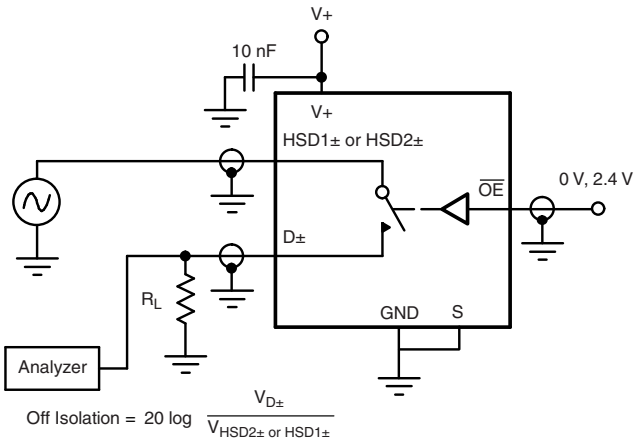


Figure 4. Off-Isolation

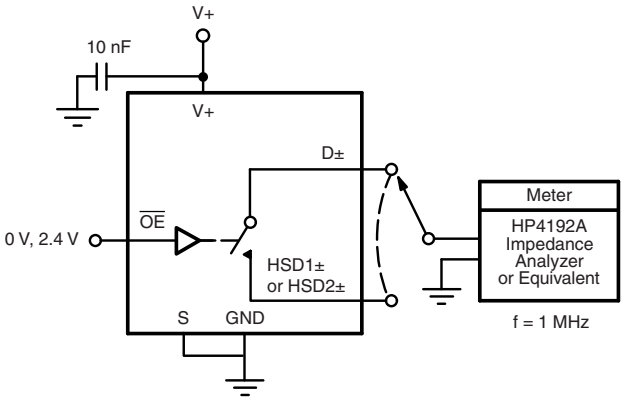
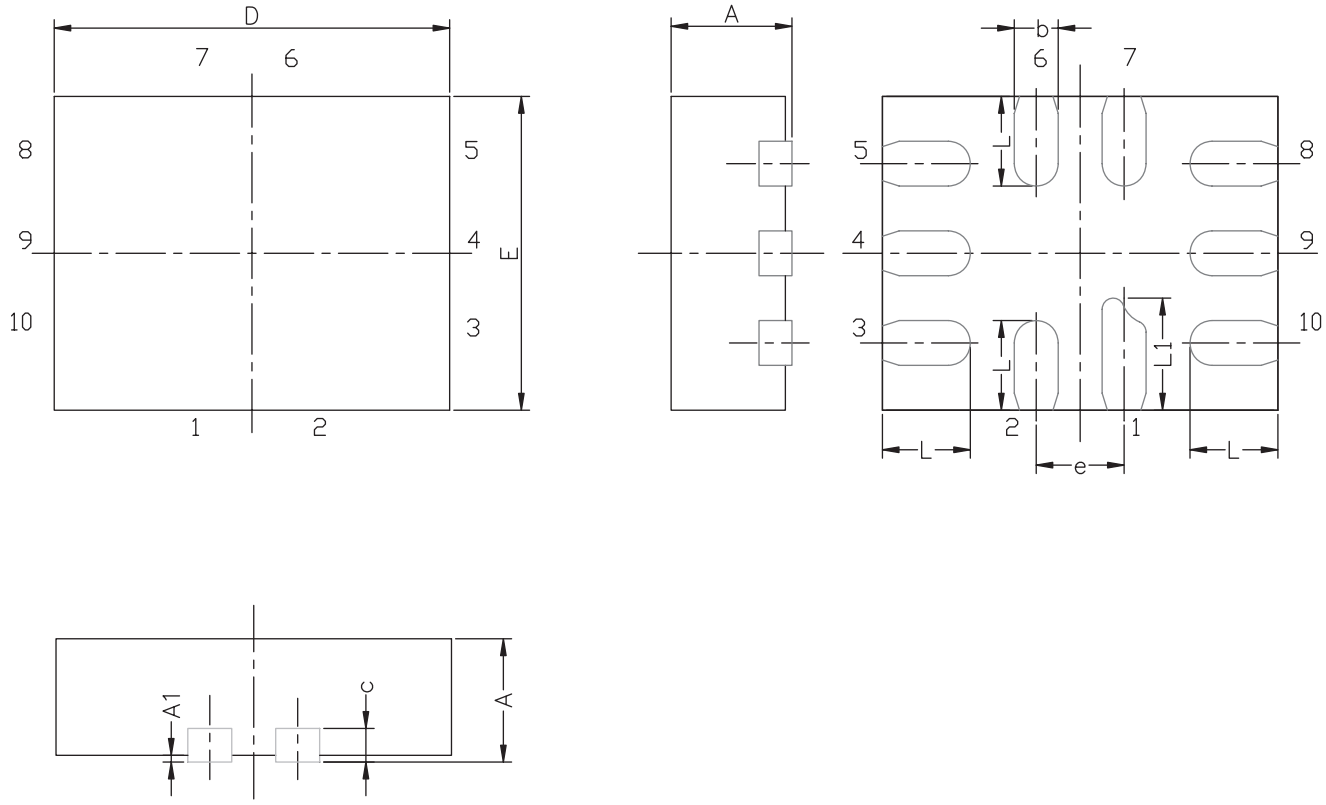


Figure 5. Channel Off/On Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?68379.

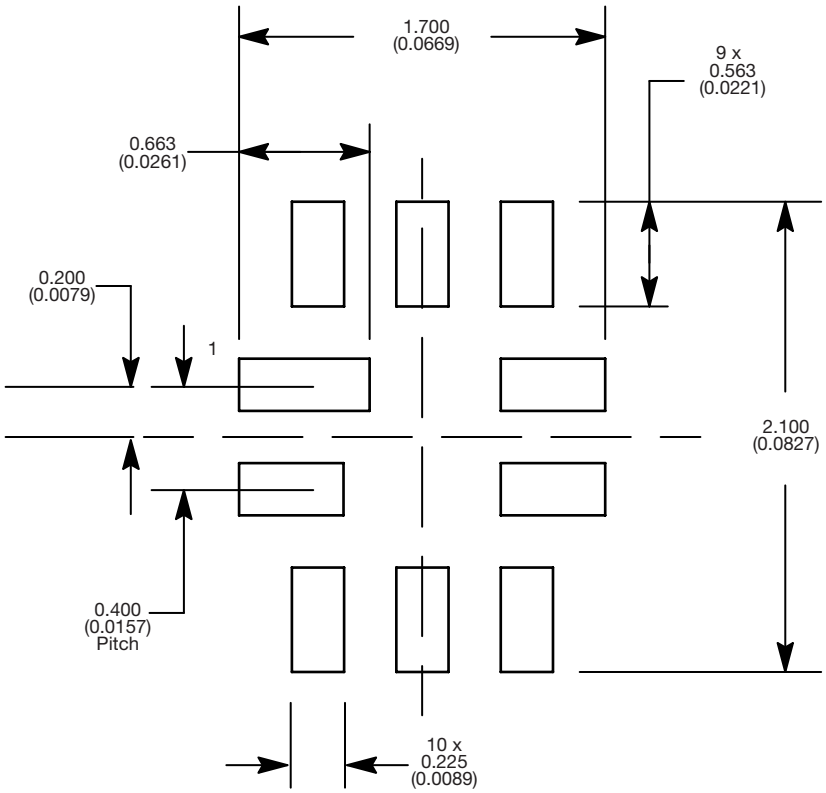
MINI QFN-10L CASE OUTLINE



DIM	MILLIMETERS			INCHES		
	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.
A	0.50	0.55	0.60	0.0197	0.0217	0.0236
A1	0.00	-	0.05	0.000	-	0.002
b	0.15	0.20	0.25	0.006	0.008	0.010
c	0.15 REF			0.006 REF		
D	1.75	1.80	1.85	0.069	0.071	0.073
E	1.35	1.40	1.45	0.053	0.055	0.057
e	0.40 BSC			0.016 BSC		
L	0.35	0.40	0.45	0.014	0.016	0.018
L1	0.45	0.50	0.55	0.0177	0.0197	0.0217

ECN T-07039-Rev. A, 12-Feb-07
DWG: 5957

RECOMMENDED MINIMUM PADS FOR MINI QFN 10L



Mounting Footprint
Dimensions in mm (inch)

Disclaimer

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as Halogen-Free follow Halogen-Free requirements as per JEDEC JS709A standards. Please note that some Vishay documentation may still make reference to the IEC 61249-2-21 definition. We confirm that all the products identified as being compliant to IEC 61249-2-21 conform to JEDEC JS709A standards.